NSN 5961-01-226-8502

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| View Online at https://aerobasegroup.com/nsn/5961-01-226-8502 |
|--|
| Inclosure Material: |
| Glass |
| Overall Length: |
| 0.357 inches |
| Terminal Length: |
| 1.000 inches |
| Overall Diameter: |
| 0.235 inches |
| Function For Which Designed: |
| Transient suppressor |
| End Application: |
| Over the horizon back scanner; los angeles class ssn (688); nimitz class cvn; arleigh burke class ddg; seawolf class ssn; emory s. Land |
| class as; supply class aoe; submarine interior comm system; sub comm and antenna systems |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation: |
| Do-13 |
| Mounting Method: |
| Terminal |
| Features Provided: |
| Hermetically sealed case |
| Criticality Code Justification: |
| Feat |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 15.8 reverse breakdown voltage, dc |
| Current Rating Per Characteristic: |
| 1.00 milliamperes forward current, average torr |
| Power Rating Per Characteristic: |
| 1.0 watts small-signal input power, common-collector major |
| Maximum Operating Tempurature Per Measurement Point: |
| 175.0 degrees celsius ambient air |
| Special Features: |
| Weapon system essential; junction pattern arrangement: pn |
| Test Data Document: |
| 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification |
| format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain |
| environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Specification Data: |
| 81349-mil-s-19500/507 government specification |
| Shelf Life: |
| N/a |

Unit Of Measure:

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Demilitarization:

No

Fiig:

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